

INTEGRATED RADIO FREQUENCY CIRCUITSAbstract of the Disclosure

5 A plurality of devices, such as devices that are
utilized for implementing radio frequency applications, can
be formed in the same substrate. Each of these devices may
be formed over a triple well that includes at least one
well capable of being biased. Each of the wells is coupled
to a well bias through a resistor. In some embodiments, a
plurality of wells operating at a relatively high frequency
may be connected to the same bias potential, each through
10 separate resistors. The noise coupling may be reduced
through the use of the bias resistors.

10/081111